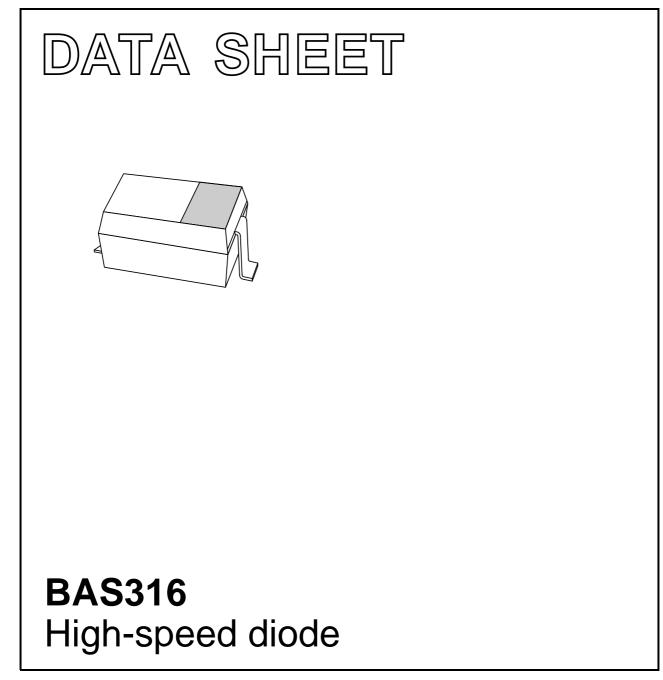
# DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 1998 Mar 26 2004 Feb 04



### Product data sheet

### **High-speed diode**

### **BAS316**

### FEATURES

- Very small plastic SMD package
- High switching speed: max. 4 ns
- Continuous reverse voltage: max. 100 V
- Repetitive peak reverse voltage: max. 100 V
- Repetitive peak forward current: max. 500 mA.

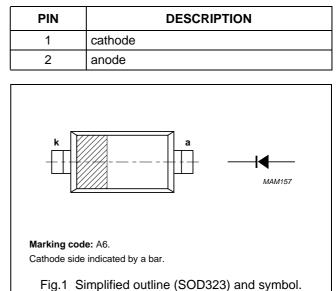
#### APPLICATIONS

• High-speed switching in e.g. surface mounted circuits.

### DESCRIPTION

The BAS316 is a high-speed switching diode fabricated in planar technology, and encapsulated in the SOD323 SMD plastic package.

### PINNING



### **ORDERING INFORMATION**

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
BAS316	<ul> <li>plastic surface mounted package; 2 leads</li> </ul>		SOD323

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>RRM</sub>	repetitive peak reverse voltage		-	100	V
V <sub>R</sub>	continuous reverse voltage		-	100	V
l <sub>F</sub>	continuous forward current	$T_s = 90 \ ^{\circ}C$ ; note 1; see Fig.2	-	250	mA
I <sub>FRM</sub>	repetitive peak forward current		-	500	mA
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; T <sub>j</sub> = 25 °C prior to surge; see Fig.4			
		t = 1 μs	_	4	А
		t = 1 ms	_	1	А
		t = 1 s	_	0.5	А
P <sub>tot</sub>	total power dissipation	T <sub>s</sub> = 90 °C; note 1	-	400	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C

### Note

1. T<sub>s</sub> is the temperature at the soldering point of the cathode tab.

### BAS316

### CHARACTERISTICS

 $T_j$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V <sub>F</sub>	forward voltage	see Fig.3		
		$I_F = 1 \text{ mA}$	715	mV
		I <sub>F</sub> = 10 mA	855	mV
		I <sub>F</sub> = 50 mA	1	V
		I <sub>F</sub> = 150 mA	1.25	V
I <sub>R</sub>	reverse current	see Fig.5		
		V <sub>R</sub> = 25 V	30	nA
		V <sub>R</sub> = 75 V	1	μA
		V <sub>R</sub> = 25 V; T <sub>j</sub> = 150 °C	30	μA
		V <sub>R</sub> = 75 V; T <sub>j</sub> = 150 °C	50	μA
C <sub>d</sub>	diode capacitance	$f = 1 \text{ MHz}; V_R = 0; \text{ see Fig.6}$	1.5	pF
t <sub>rr</sub>	reverse recovery time	when switched from $I_F = 10$ mA to $I_R = 10$ mA; $R_L = 100 \Omega$ ; measured at $I_R = 1$ mA; see Fig.7	4	ns
V <sub>fr</sub>	forward recovery voltage	when switched from $I_F = 10$ mA; $t_r = 20$ ns; see Fig.8	1.75	V

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th(j-s)</sub>	thermal resistance from junction to soldering point	note 1	150	K/W

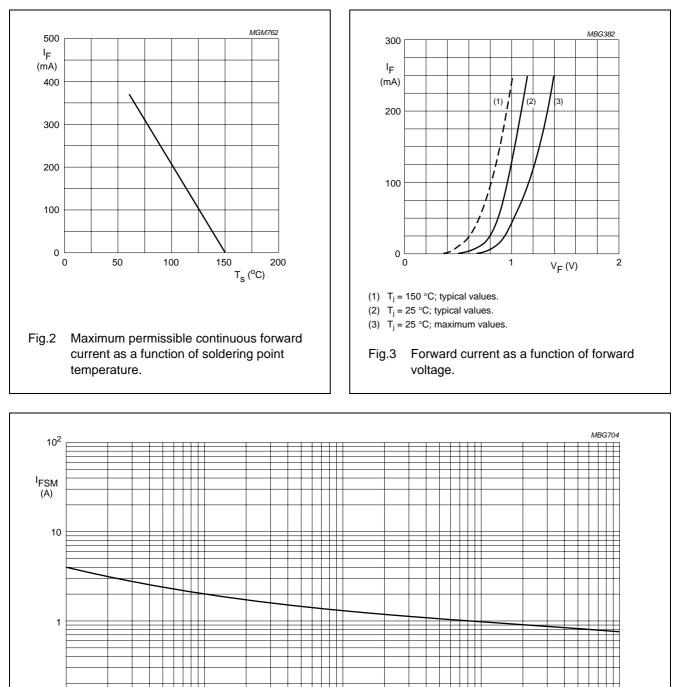
### Note

1. Soldering point of the cathode tab.

### Product data sheet

### BAS316





Based on square wave currents.

10

 $T_j = 25 \ ^{\circ}C$  prior to surge.

Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration.

10<sup>2</sup>

10<sup>3</sup>

10<sup>4</sup>

t<sub>p</sub> (μs)

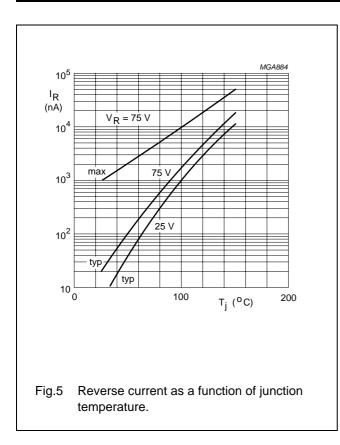
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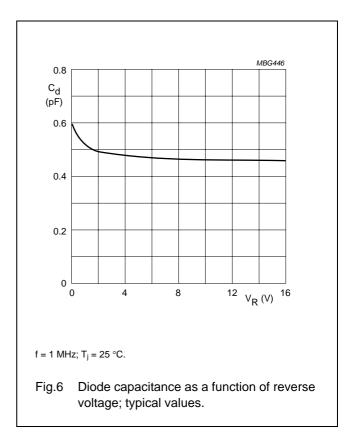
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### Product data sheet

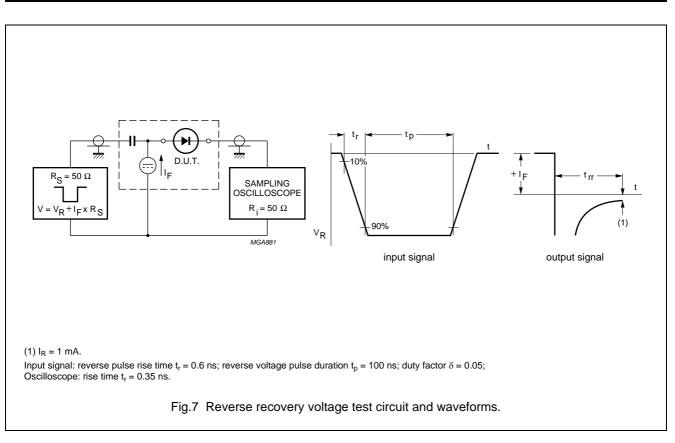
# High-speed diode

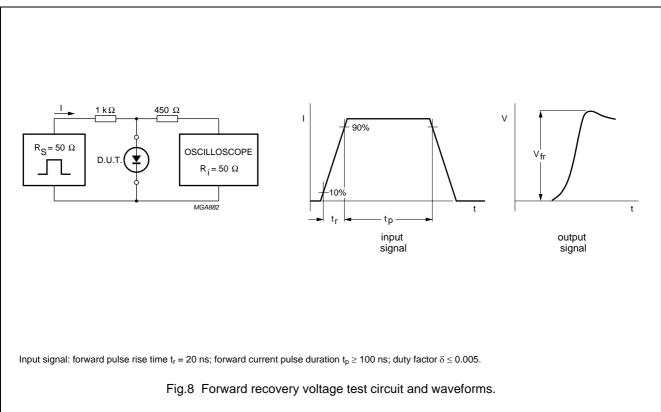
# BAS316





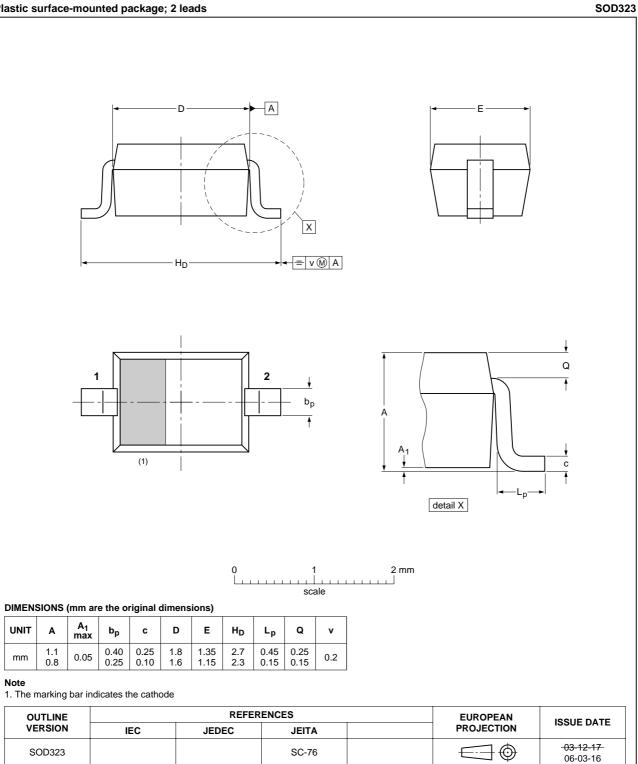
### BAS316





### **PACKAGE OUTLINE**





**BAS316** 

**BAS316** 

### DATA SHEET STATUS

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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## **NXP Semiconductors**

#### **Customer notification**

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

#### **Contact information**

For additional information please visit: http://www.nxp.com For sales offices addresses send e-mail to: salesaddresses@nxp.com

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